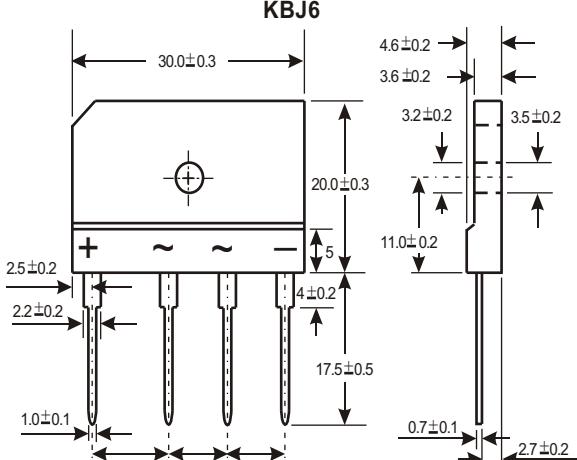


SILICON BRIDGE RECTIFIERS

Reverse Voltage - 50 to 1000 Volts Forward Current - 15.0 Amperes

 <p><i>Dimensions in inches and (millimeters)</i></p>	<p>FEATURES</p> <ul style="list-style-type: none"> • This series is UL listed under the Recognized Component Index, file number E142814 • Plastic package has Underwriters Laboratory Flammability Classification 94V-0 • High case dielectric strength of 1500VRMS Ideal for printed circuit boards • High surge current capability <p>MECHANICAL DATA</p> <p>Case : Molded plastic body over passivated junctions Terminals : Plated leads solderable per MIL-STD-750, Method 2026 Polarity : Polarity symbols molded on body Mounting Position : Any(3) Mounting Torque : 5 in-lbs max. Weight : 0.26 ounce, 7.0 grams (approx)</p>
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MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave 60Hz, resistive or inductive load, for current capacitive load, derate by 20%.

Catalog Number	SYMBOLS	GBJ 15005	GBJ 1501	GBJ 1502	GBJ 1504	GBJ 1506	GBJ 1508	GBJ 1510	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	VOLTS
Maximum average forward output rectified current at $T_c=50^\circ\text{C}$ (Note 1,2)	$I_{(AV)}$				15				Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}				240.0				Amps
Rating for Fusing($t < 8.3\text{ms}$)	I^2t				240				A^2s
Maximum instantaneous forward voltage drop per bridge element at 12.5A	V_F				1.1				Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R			10					μA
				1.0					mA
Isolation voltage from case to leads	V_{ISO}			2500					V_{AC}
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$			0.8					$^\circ\text{C}/\text{W}$
Operating junction temperature range	T_J			-55 to +150					$^\circ\text{C}$
storage temperature range	T_{STG}			-55 to +150					$^\circ\text{C}$

Notes: (1) Device mounted on 250mm x 250mm x 20mm aluminum plate heatsink.

RATINGS AND CHARACTERISTIC CURVES GBJ15005 THRU GBJ1510

Fig. 1 Derating Curve for Output Rectified Current

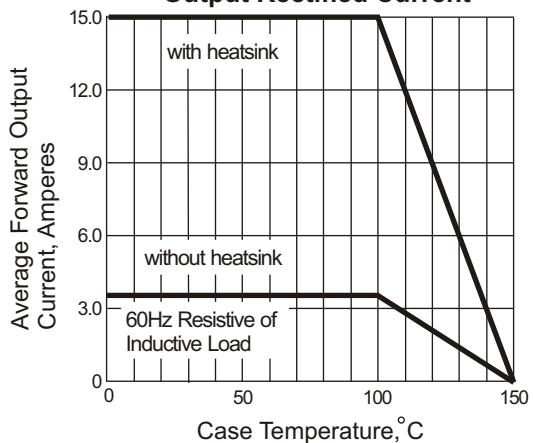


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

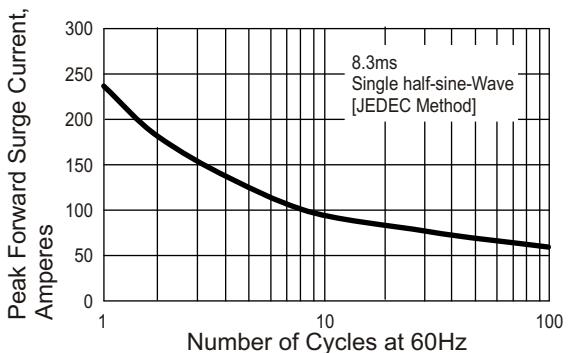


Fig. 3 Typical Instantaneous Forward Characteristics

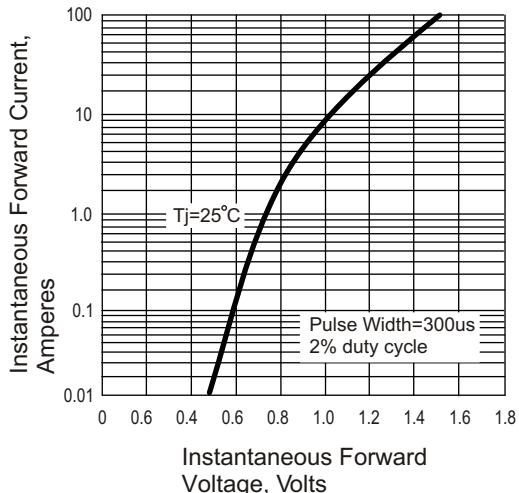


Fig. 4 Typical Reverse Characteristics at T_j=25°C

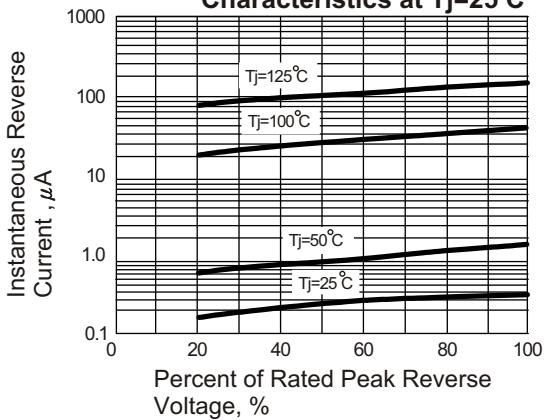


Fig. 5 Typical Junction Capacitance

